

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

MCH3456 — General-Purpose Switching Device **Applications**

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 1.5V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|--------|---|-------------|------|
| Drain-to-Source Voltage | VDSS | | 15 | V |
| Gate-to-Source Voltage | VGSS | | ±10 | V |
| Drain Current (DC) | ID | | 1.8 | Α |
| Drain Current (Pulse) | IDP | PW≤10μs, duty cycle≤1% | 7.2 | Α |
| Allowable Power Dissipation | PD | Mounted on a ceramic board (900mm²X0.8mm) | 0.8 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | 1.1 |
|--|-----------------------|---|---------|-----|-----|------|
| | | | min | typ | max | Unit |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | ID=1mA, VGS=0V | 15 | | | V |
| Zero-Gate Voltage Drain Current | IDSS | V _{DS} =15V, V _{GS} =0V | | | 1 | μА |
| Gate-to-Source Leakage Current | IGSS | V _{GS} =±8V, V _{DS} =0V | | | ±10 | μА |
| Cutoff Voltage | VGS(off) | VDS=10V, ID=1mA | 0.4 | | 1.3 | V |
| Forward Transfer Admittance | yfs | V _{DS} =10V, I _D =1A | 1.5 | 2.6 | | S |
| Static Drain-to-Source On-State Resistance | R _{DS} (on)1 | I _D =1A, V _G S=4V | | 120 | 160 | mΩ |
| | RDS(on)2 | ID=0.5A, VGS=2.5V | | 165 | 240 | mΩ |
| | R _{DS} (on)3 | I _D =0.1A, V _G S=1.8V | | 230 | 350 | mΩ |
| | R _{DS} (on)4 | I _D =0.1A, V _G S=1.5V | | 310 | 750 | mΩ |
| Input Capacitance | Ciss | VDS=10V, f=1MHz | | 105 | | pF |
| Output Capacitance | Coss | V _{DS} =10V, f=1MHz | | 30 | | pF |
| Reverse Transfer Capacitance | Crss | V _{DS} =10V, f=1MHz | | 24 | | pF |
| Turn-ON Delay Time | t _d (on) | See specified Test Circuit. | | 7.8 | | ns |
| Rise Time | t _r | See specified Test Circuit. | | 27 | | ns |
| Turn-OFF Delay Time | t _d (off) | See specified Test Circuit. | | 18 | | ns |
| Fall Time | tf | See specified Test Circuit. | | 22 | | ns |

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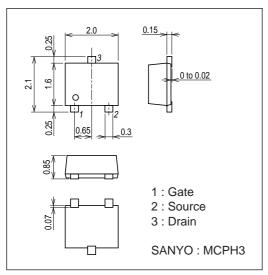
MCH3456

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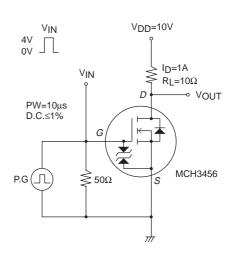
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|-------------------------------|--------|---|---------|------|-----|------|
| | Symbol | | min | typ | max | Onne |
| Total Gate Charge | Qg | V _{DS} =10V, V _{GS} =4V, I _D =1.8A | | 1.86 | | nC |
| Gate-to-Source Charge | Qgs | V _{DS} =10V, V _{GS} =4V, I _D =1.8A | | 0.33 | | nC |
| Gate-to-Drain "Miller" Charge | Qgd | V _{DS} =10V, V _{GS} =4V, I _D =1.8A | | 0.55 | | nC |
| Diode Forward Voltage | VSD | IS=1.8A, VGS=0V | | 0.88 | 1.2 | V |

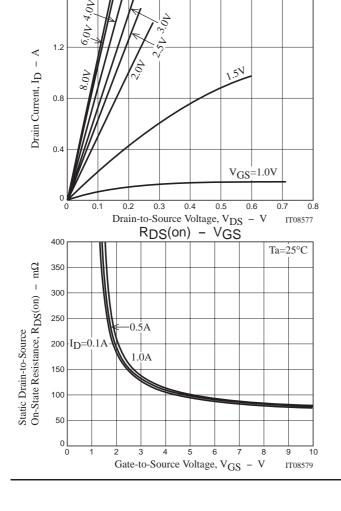
Package Dimensions

unit : mm 7019A-003

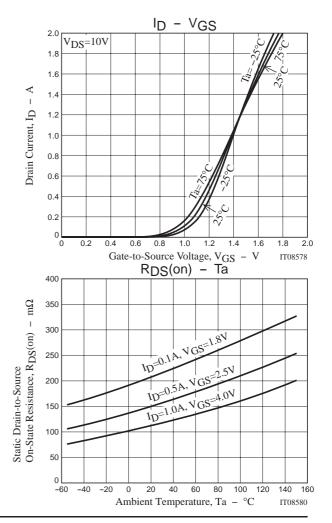


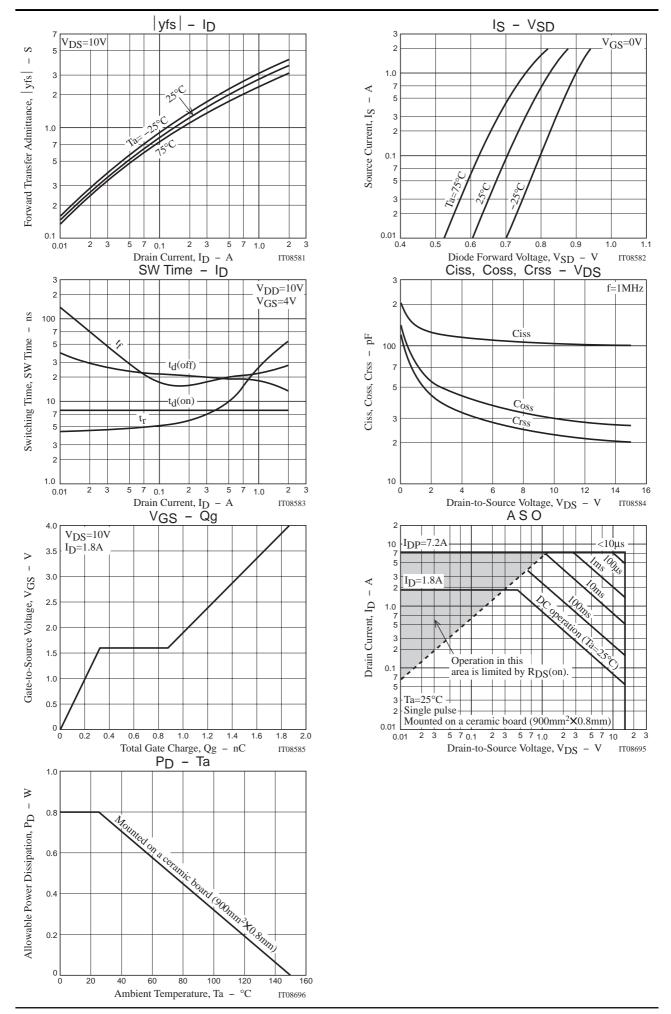
Switching Time Test Circuit





ID - VDS





Note on usage: Since the MCH3456 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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